

#### **GENERAL DESCRIPTION**

The CM2854 family is positive, linear regulators featured low quiescent current ( $30\mu A$  typ.) with low dropout voltage, making them ideal for battery applications. The space-saving SOT-23-6 package is attractive for "Pocket" and "Hard Held" applications.

These rugged devices have both Thermal Shutdown, and Current Fold-back to prevent device failure under the "Worst" of operating conditions.

An additional feature is a "Power Good" detector, which pulls low when the output is out of regulation.

The CM2854 is stable with an output capacitance of  $2.2\mu F$  or greater.

# **FEATURES**

- Very Low Dropout Voltage
- ♦ Low Current Consumption: Typ. 30μA, Max. 35μA
- ♦ High Accuracy Output Voltage: +/- 1.5%
- Guaranteed 150mA Output
- ♦ Input Range of 2.6V to 7.0V
- Thermal Shutdown
- Current Limiting
- Power Good Output Function
- Compact Package: SOT-23-6
- Adjustable Output Voltages
- ♦ Short Circuit Current Fold-Back
- ◆ Low Temperature Coefficient

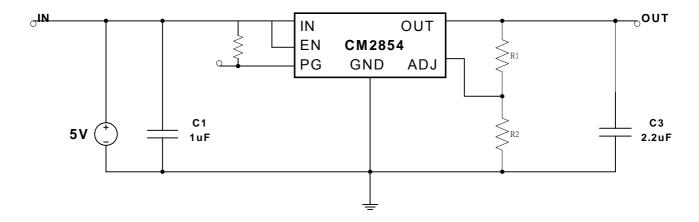
#### **APPLICATIONS**

- Battery-powered devices
- Personal communication devices
- ♦ Home electric/electronic appliances
- PC peripherals

# 24 Hours Technical Support--WebSIM

Champion provides customers an online circuit simulation tool called WebSIM. You could simply logon our website at www.champion-micro.com for details.

#### TYPICAL APPLICATIONS

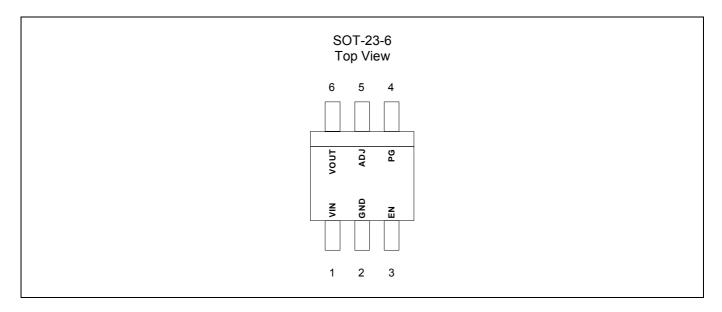


Note: 1. Suggest to add a small Cap 100pF between OUT and connection of R1and R2 to get less VOUT ripple Vout = Vref \* (1 + R1/R2); Vref = 1.176V

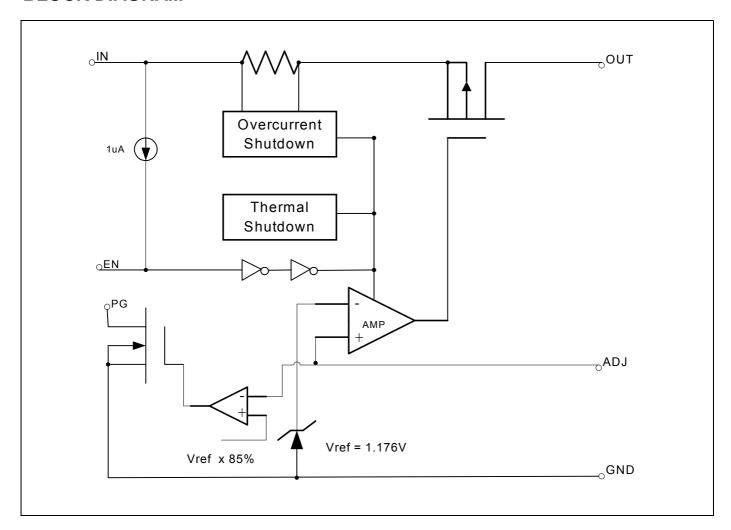
2. Enable pin can not be floating.



# **PIN CONFIGURATION**



## **BLOCK DIAGRAM**



## ORDERING INFORMATION

Part Number	Output Voltage	Temperature Range	Package
CM2854IM26	Adjustable	-40°C ~ +85°C	SOT-23-6

## **ABSOLUTE MAXIMUM RATINGS**

## **OPERATING RATINGS**

Input Voltage+7V	Ambient Temperature Range (T <sub>A</sub> )40° to +85° €
Output Current P <sub>D</sub> / (V <sub>IN</sub> - Vo)	Junction Temperature Range40°C to +125°C
Output Voltage GND-0.3V to V <sub>IN</sub> +0.3V	
ESD Classification B	

# THERMAL INFORMATION

Parameter		Maximum	Unit
Thermal Resistance (⊖ <sub>JA</sub> )	SOT-23-6	260	°C <b>W</b>
Internal Power Dissipation (P <sub>D</sub> )	SOT-23-6	Note 1	
Maximum Junction Temperature		150	$^{\circ}\!\mathbb{C}$
Maximum Lead Temperature (10 Sec)		300	$^{\circ}\!\mathbb{C}$

Caution: Stress above the listed absolute rating may cause permanent damage to the device.

**Note 1**:  $P_{D(MAX)} = (T_{J(MAX)} - T_A)/\theta_{JA}$ , where  $\theta_{JA}$  depends on the printed circuit layout.

# **ELECTRICAL CHARACTERISTICS**

 $T_A = +25$ °C;  $V_{IN} = V_{IN(MIN)}$  unless otherwise noted

		Test Conditions		CM2854					
Parameter	Symbol			Min.	Тур.	Max.	Unit		
Input Voltage	V <sub>IN</sub>			Note 2		7	V		
Output Voltage Accuracy	V <sub>OUT</sub>	I <sub>O</sub> = 1	1mA		-1.5		1.5	%	
		4504		/< V <sub>O(NOM)</sub> <=2.0V			1300		
	V <sub>DROPOUT</sub>	I <sub>O</sub> = 150mA,	2.0\	/< V <sub>O(NOM)</sub> <=2.5V			800	mV	
		V <sub>OUT</sub> =V <sub>O(NOM)</sub> -1.5%,		2.5V< V <sub>O(NOM)</sub>			300		
Output Current	Io	V <sub>OUT</sub> > 1.2V		300			mA		
Current Limit	I <sub>LIM</sub>	V <sub>OUT</sub> >	1.2	V		800		mA	
Short Circuit Current	I <sub>SC</sub>	V <sub>OUT</sub> < 0.8\	√ <b>(N</b>	ote 3)		150		mA	
Quiescent Current	IQ	I <sub>O</sub> = (	)mA			30	35	$\mu$ A	
Ground Pin Current	I <sub>GND</sub>	I <sub>O</sub> = 1mA t	to 15	50mA		30	35	$\mu$ A	
Bandgap Reference	$V_{REF}$	$V_0 = V_{REF}$ , Io	oad :	= 10mA	1.168	1.176	1.184	V	
		  I <sub>OUT</sub> =1mA, V <sub>IN</sub> =V <sub>OUT</sub> +1	to	V <sub>OUT</sub> < 2.0V	-0.1	0.02	0.1	%	
Line Regulation	REG <sub>LINE</sub>			2.0V <v<sub>OUT &lt; 3.0V</v<sub>	015	0.03	0.15	%	
V <sub>OUT</sub> +2		3.0V <v<sub>OUT</v<sub>	-0.3	0.06	0.3	%			
Load Regulation	REG <sub>LOAD</sub>	I <sub>O</sub> =1mA to 150mA			0.2	1	%		
Over Temperature Shutdown	OTS					150		$^{\circ}\!\mathbb{C}$	
Over Temperature Hysteresis	OTH					30		$^{\circ}\!\mathbb{C}$	
V <sub>OUT</sub> Temperature Coefficient	TC					25		ppm/°C	
		I <sub>O</sub> = 100mA		f=1kHz		60			
Power Supply Rejection	PSRR	C <sub>o</sub> =2.2µF ceramic		f=10kHz		50		dB	
				f=100kHz		40			
Output Voltage Noise	eN	f=10Hz to 100kHz		C <sub>O</sub> =2.2µF		30		$\mu$ Vrms	
- Catput Voltage Holde	011	I <sub>O</sub> = 10mA		·				μ ντιτισ	
EN Input Bias Current	I <sub>EH</sub>	$V_{EN}=V_{IN}$ , $V_{IN}=2.7V$ to 7V				0.1	$\mu$ A		
p	I <sub>EL</sub>	·	$V_{EN}$ =0V, $V_{IN}$ =2.7V to 7V			1.0	3.0	$\mu$ A	
EN Input Threshold	V <sub>EH</sub>		V <sub>IN</sub> =2.7V to 7V			V <sub>IN</sub> /2+0.8V	$V_{IN}$	V	
	V <sub>EL</sub>	V <sub>IN</sub> =2.7V to 7V		0	V <sub>IN</sub> /2-0.8V		V		
Shutdown Supply Current	I <sub>SD</sub>	$V_{IN}$ =5.0V, $V_{OUT}$ =0V, $V_{EN}$ < $V_{EL}$		_	2.0		μΑ		
Shutdown Output Voltage	V <sub>O, SD</sub>	I <sub>O</sub> =150mA		0		0.1	V		
PG Leakage Current	I <sub>LC</sub>	V <sub>PG</sub> = 7V				1	$\mu$ A		
PG Voltage Rating	$V_{PG}$	V <sub>OUT</sub> in regulation				7	V		
PG Low Threshold		% of V <sub>O</sub> (PG ON)		89.5			%		
PG High Threshold		% of V <sub>O</sub> (PG OFF)				96.5	%		
PG Voltage Low	V <sub>OL</sub>	I <sub>SINK</sub> = 2mA				0.1	V		
Delay Time to PG (Note 3)	t <sub>DELAY</sub>	V <sub>IN</sub> =				7.8		ms	
Note 2 \/ = \/ + \/	*DLLAT	V <sub>IN</sub> = 3V			3.8		ms		

Note 2.  $V_{\text{IN}(\text{MIN})} = V_{\text{OUT}} + V_{\text{DROPOUT}}$ Note 3. Guaranteed by Design, not 100% test. VIN start time needs to be less than 2ms. Note 4. Short Circuit Current and Current limit value will increase as input voltage is larger than  $V_{\text{IN}(\text{MIN})}$ 



# CM2854 150mA CMOS LDO WITH EN & PG

#### **DETAILED DESCRIPTION**

The CM2854 family of CMOS regulators contain a PMOS pass transistor, voltage reference, error amplifier, over-current protection, output short circuit protection, thermal shutdown, and power good function.

The P-channel pass transistor receives data from the error amplifier, over-current shutdown, short output protection, and thermal protection circuits. During normal operation, the error amplifier compares the output voltage to a precision reference. Over-current and Thermal shutdown circuits become active when the junction temperature exceeds  $150^{\circ}$ C, or the current exceeds 150mA. During thermal shutdown, the output voltage remains low. Normal operation is restored when the junction temperature drops below  $120^{\circ}$ C.

The CM2854 switches from voltage mode to current mode when the load exceeds the rated output current. This prevents over-stress. The CM2854 also incorporates current fold-back to reduce power dissipation when the output is short-circuited. This feature becomes active when the output drops below 0.95V, and reduces the current flow by 65%. Full current is restored when the voltage exceeds 0.95V.

#### **EXTERNAL CAPACITOR**

The CM2854 is stable with an output capacitor to ground of 2.2µF or greater. It can keep stable even with higher or poor ESR capacitors. A second capacitor is recommended between the input and ground to stabilize VIN. The input capacitor should be larger than 0.1µF to have a beneficial effect. All capacitors should be placed in close proximity to the pins. A "quiet" ground termination is desirable.

#### **ENABLE**

When actively, pulled low, the PMOS pass transistor shut off, and all internal circuits are powered down. In this state, the quiescent current is less than 1µA. This pin behaves much like an electronic switch.

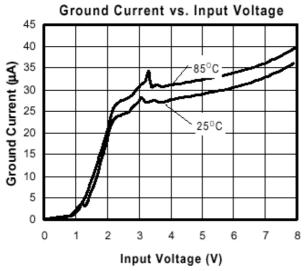
#### POWER GOOD

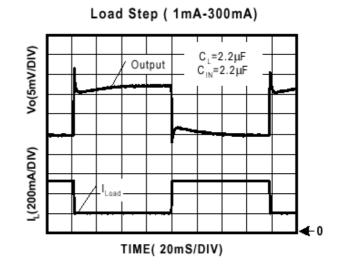
The CM2854 includes the Power Good feature. Normally, Pin 4 is floating, however, when the output is lower than 85% of the specified voltage, it pulls low. This can occur under the following conditions:

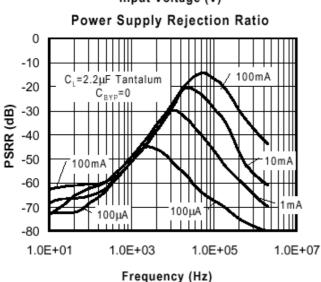
- 1) Input Voltage too low
- 2) During Over-Temperature
- 3) During Over-Current

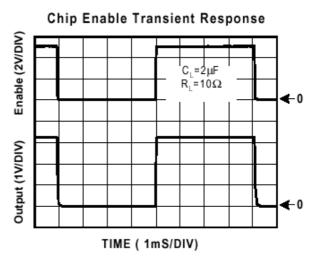


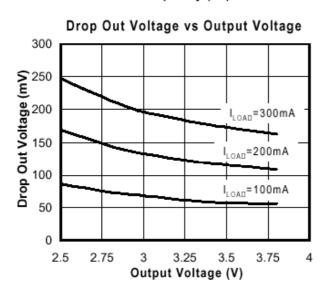
#### TYPICAL ELECTRICAL CHARACTERISTICS

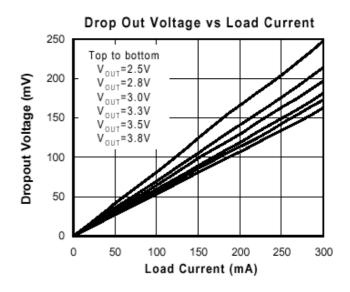






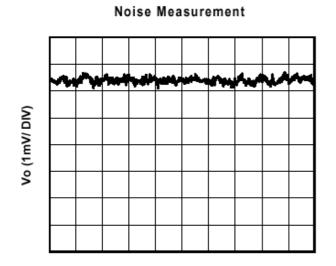




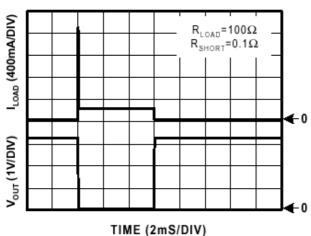


8.0



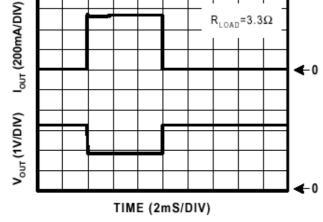


TIME (20mS/DIV) Short Circuit Response



**Current Limit Response** 

 $R_{LOAD} = 3.3\Omega$ 



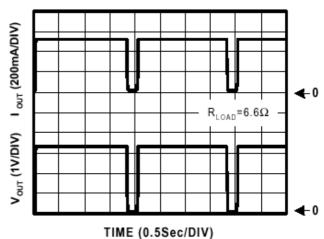
Safe Operating Area SOT-26 Output Current (mA) 300 100 10

Input-Output Voltage Differential (V)

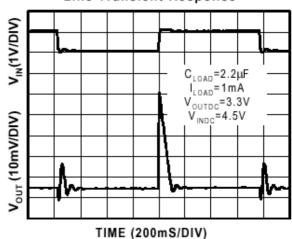
1.0

#### Overtemperature Shutdown

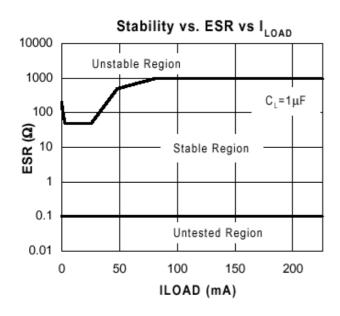
0.1

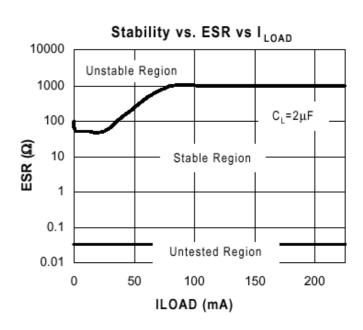


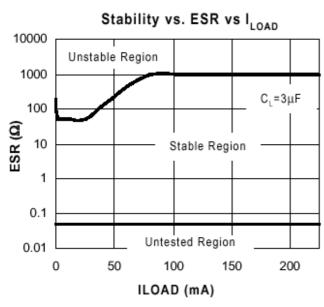
Line Transient Response

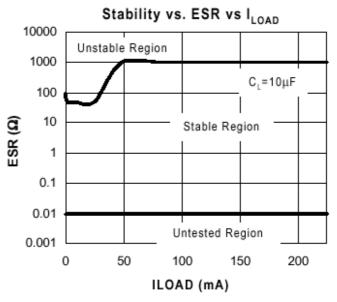






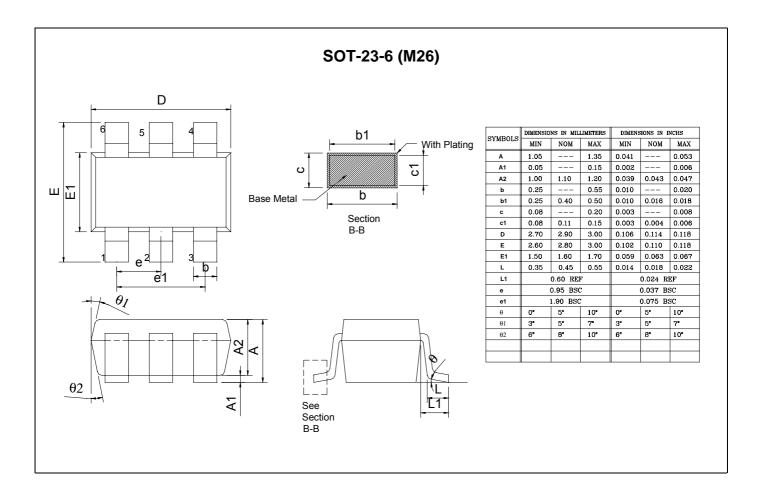








## **PACKAGE DIMENSION**





# CM2854 150mA CMOS LDO WITH EN & PG

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